BLP8G10S-45P; BLP8G10S-45PG

Power LDMOS transistor

AMPLEON

Rev. 3 — 8 January 2016

Product data sheet

1. Product profile

1.1 General description

The BLP8G10S-45P and BLP8G10S-45PG are dual path, 45 W LDMOS power transistors for base station applications at frequencies from 700 MHz to 1000 MHz.

Table 1. Application performance

Typical RF performance at T_{case} = 25 °C; I_{Dq} = 224 mA in common source class-AB production circuit.

Test signal	f	V _{DS}	P _{L(AV)}	G _p	η_{D}	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	960	28	2.5	20.8	19.8	-49 <u>[1]</u>

^[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 8.4 dB at 0.01% probability on CCDF; carrier spacing = 5 MHz; per section unless otherwise specified.

1.2 Features and benefits

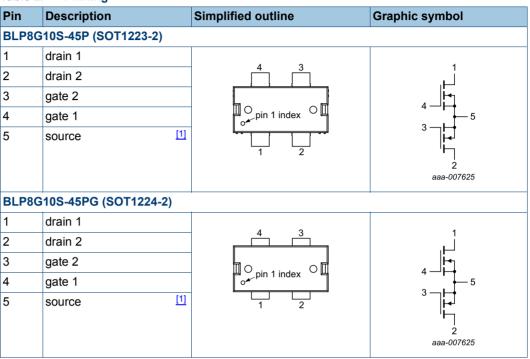
- High efficiency
- Excellent ruggedness
- Designed for broadband operation (700 MHz to 1000 MHz)
- Excellent thermal stability
- High power gain
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- W-CDMA
- LTE
- GSM

2. Pinning information

Table 2. Pinning



[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package	ackage				
	Name	Description	Version			
BLP8G10S-45P	HSOP4F	plastic, heatsink small outline package; 4 leads (flat)	SOT1223-2			
BLP8G10S-45PG	HSOP4	plastic, heatsink small outline package; 4 leads	SOT1224-2			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	65	V
V_{GS}	gate-source voltage	-0.5	+13	V
T _{stg}	storage temperature	- 65	+150	°C
Tj	junction temperature [1]	-	225	°C
T _{case}	case temperature [1]	-	150	°C

[1] Continuous use at maximum temperature will affect the reliability.

5. Thermal characteristics

Table 5. Thermal characteristics

Values specified for entire device.

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-case)}	thermal resistance from junction to case	T _{case} = 85 °C; P _L = 5 W	0.85	K/W

6. Characteristics

Table 6. DC characteristics

 T_{case} = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.4 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 40 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V	-	-	1.4	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	7.3	-	А
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 2 A	-	3.0	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{DS} = 10 \text{ V}; I_D = 1.4 \text{ A}$ $V_{GS} = V_{GS(th)} + 3.75 \text{ V}$	-	500	-	mΩ

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR 8.4 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1-64 DPCH; f_1 = 952.5 MHz; f_2 = 957.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 224 mA; T_{case} = 25 °C; per section in a class-AB production circuit unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	P _L = 2.5 W	20	20.8	-	dB
RLin	input return loss	P _L = 2.5 W	-	-18	-9	dB
η_{D}	drain efficiency	P _L = 2.5 W	18	19.8	-	%
ACPR	adjacent channel power ratio	P _L = 2.5 W	-	-49	-43	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLP8G10S-45P and BLP8G10S-45PG are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 224 \text{ mA}$; $P_L = 25 \text{ W}$; f = 728 MHz.

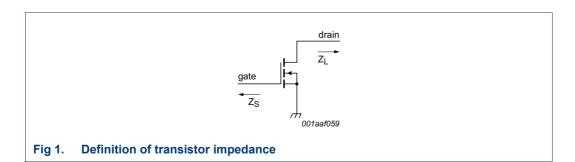
7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data. Typical values per section unless otherwise specified.

f	Z _S [1]	Z _L [1][2]
(MHz)	(Ω)	(Ω)
BLP8G10S-45P		
720	11.6 – j12.9	5.44 + j6.34
746	14.8 – j9.2	4.51 + j6.03
757	15.3 – j4.6	4.23 + j6.15
791	13.3 – j1.6	3.99 + j5.62
820	6.5 – j1.1	3.87 + j5.37
869	5.2 – j2.4	4.25 + j4.49
894	4.4 – j3.0	3.69 + j4.89
925	3.8 – j3.9	3.49 + j4.72
942	3.6 – j4.2	3.06 + j4.46
960	3.6 – j4.7	3.29 + j4.04
BLP8G10S-45PG		
720	13.2 – j7.7	4.34 + j5.10
746	11.8 – j4.6	4.58 + j4.94
757	10.4 – j3.7	4.50 + j5.34
791	9.8 – j2.5	4.19 + j4.87
869	5.0 – j4.0	4.27 + j3.42
881	4.6 – j4.2	3.62 + j3.45
894	4.2 – j4.7	3.77 + j3.29
925	3.8 – j5.6	3.60 + j3.15
942	3.7 – j5.8	3.29 + j2.89
961	3.6 – j6.4	3.36 + j2.47

- [1] Z_S and Z_L defined in Figure 1.
- [2] Z_L is selected for maximum efficiency.



7.3 Test circuit

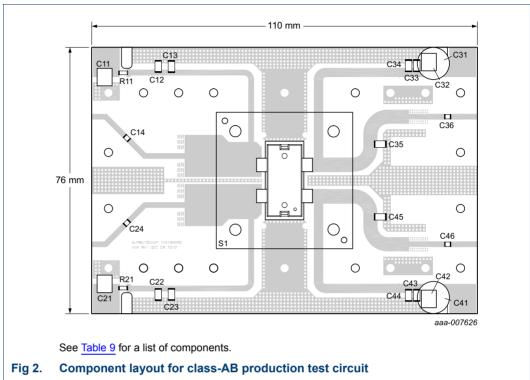
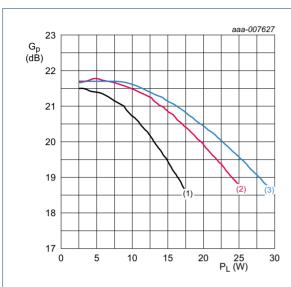


Table 9. List of components For test circuit see Figure 2.

Component	Description	Value	Remarks
C11, C21, C32, C42	multilayer ceramic chip capacitor	10 μF, 50 V	
C12, C22, C33, C43	multilayer ceramic chip capacitor	1 μF, 50 V	
C13, C23, C34, C44	multilayer ceramic chip capacitor	43 pF	ATC100B
C14, C24, C36, C46	multilayer ceramic chip capacitor	43 pF	ATC100A
C31, C41	electrolytic capacitor	220 μF, 63 V	
C35, C45	multilayer ceramic chip capacitor	3.3 pF	ATC100B
R11, R21	chip resistor	10 Ω	Multi Comp SMD 1206
S1	socket	-	Johnstech

7.4 Graphical data

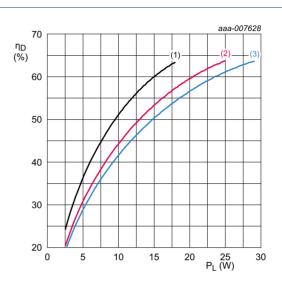
7.4.1 2-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $V_{DS} = 24 \text{ V}$
- (2) $V_{DS} = 28 \text{ V}$
- (3) $V_{DS} = 32 V$

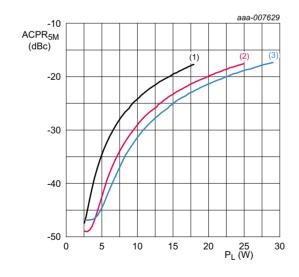
Fig 3. Power gain as a function of output power per section; typical values



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $V_{DS} = 24 \text{ V}$
- (2) $V_{DS} = 28 \text{ V}$
- (3) $V_{DS} = 32 V$

Fig 4. Drain efficiency as a function of output power per section; typical values

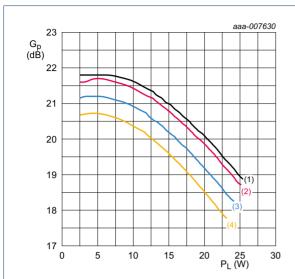


 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $V_{DS} = 24 \text{ V}$
- (2) $V_{DS} = 28 \text{ V}$
- (3) $V_{DS} = 32 V$

Fig 5. Adjacent channel power ratio (5 MHz) as a function of output power per section; typical values

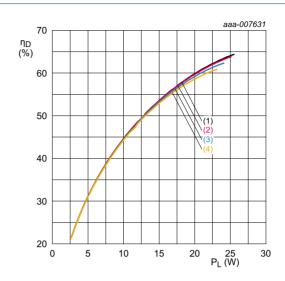
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 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $T_{case} = 15 \,^{\circ}C$
- (2) $T_{case} = 25 \, ^{\circ}C$
- (3) $T_{case} = 55 \, ^{\circ}C$
- (4) $T_{case} = 85 \, ^{\circ}C$

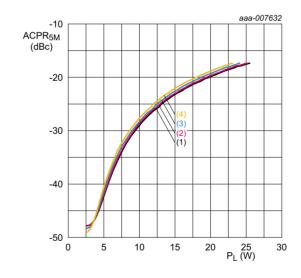
Fig 6. Power gain as a function of output power per section; typical values



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $T_{case} = 15 \, ^{\circ}C$
- (2) $T_{case} = 25 \, ^{\circ}C$
- (3) $T_{case} = 55 \, ^{\circ}C$
- (4) $T_{case} = 85 \, ^{\circ}C$

Fig 7. Drain efficiency as a function of output power per section; typical values



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $T_{case} = 15 \,^{\circ}C$
- (2) $T_{case} = 25 \, ^{\circ}C$
- (3) $T_{case} = 55 \, ^{\circ}C$
- (4) $T_{case} = 85 \, ^{\circ}C$

Fig 8. Adjacent channel power ratio (5 MHz) as a function of output power per section; typical values

8. Package outline

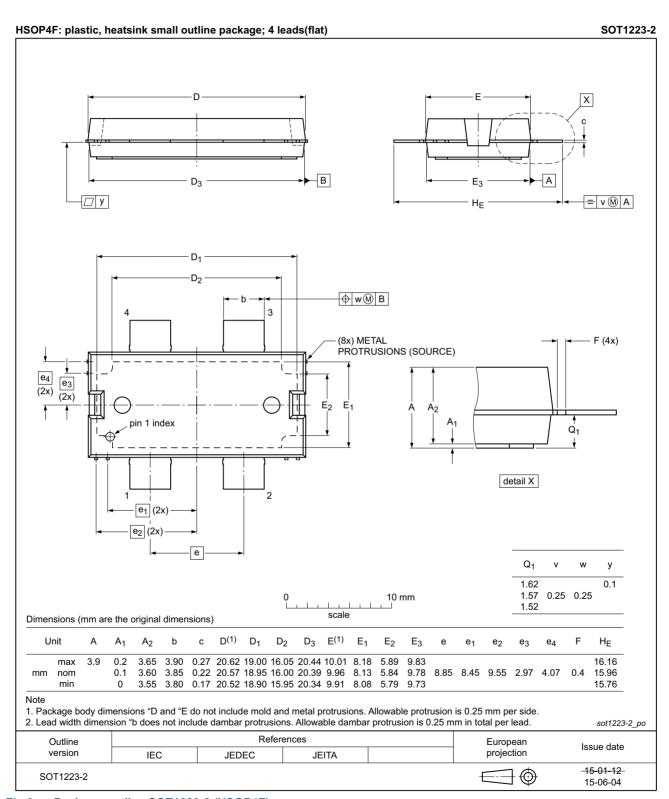


Fig 9. Package outline SOT1223-2 (HSOP4F)

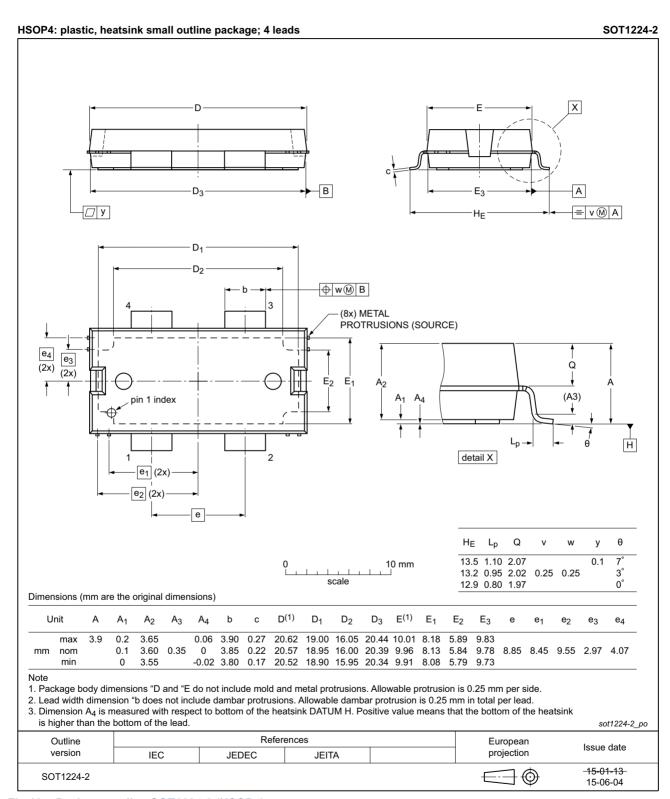


Fig 10. Package outline SOT1224-2 (HSOP4)

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
GSM	Global System for Mobile Communications
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LTE	Long Term Evolution
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP8G10S-45P_8G10S-45PG v.3	20160108	Product data sheet		BLP8G10S-45P_8G10S-45PG v.2
Modifications:	Table 2 on	page 2: table updat	ed	
	• Table 3 on	page 2: table updat	ed	
	• Figure 9 o	n page 8: package o	utline changed fro	om SOT1223-1 to SOT1223-2
	• Figure 10	on page 9: package	outline changed t	from SOT1224-1 to SOT1224-2
BLP8G10S-45P_8G10S-45PG v.2	20150901	Product data sheet		BLP8G10S-45P_8G10S-45PG
				v.1
BLP8G10S-45P_8G10S-45PG v.1	20130725	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Power LDMOS transistor

14. Contents

1	Product profile 1
1.1	General description 1
1.2	Features and benefits
1.3	Applications
2	Pinning information 2
3	Ordering information 2
4	Limiting values 2
5	Thermal characteristics 3
6	Characteristics 3
7	Test information
7.1	Ruggedness in class-AB operation 3
7.2	Impedance information 4
7.3	Test circuit
7.4	Graphical data 6
7.4.1	2-Carrier W-CDMA 6
8	Package outline 8
9	Handling information 10
10	Abbreviations
11	Revision history 10
12	Legal information 11
12.1	Data sheet status
12.2	Definitions 11
12.3	Disclaimers
12.4	Trademarks 12
13	Contact information 12
14	Contents

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